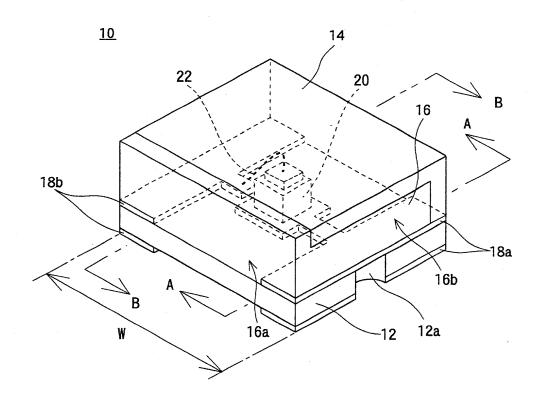
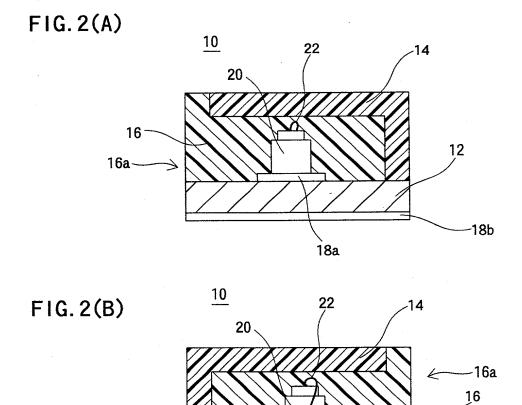
FIG. 1



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-18a

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18b

FIG. 3(A)

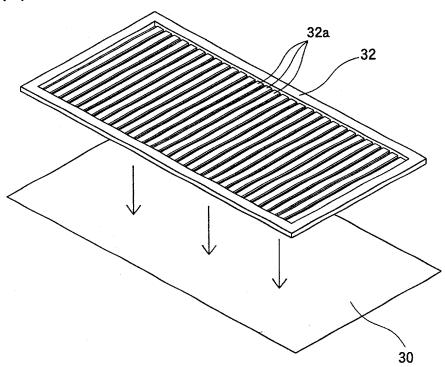
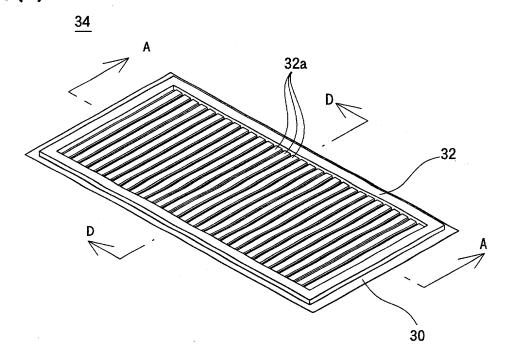


FIG. 3(B)



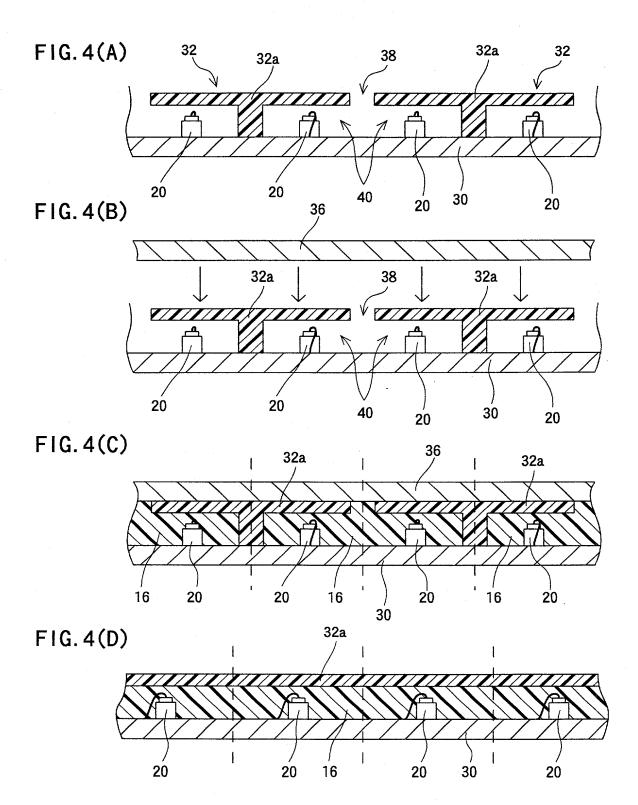


FIG. 5

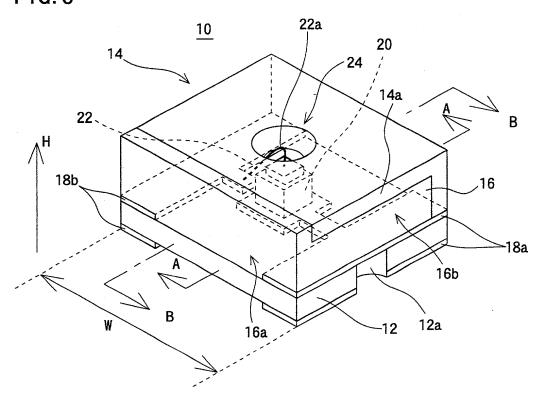
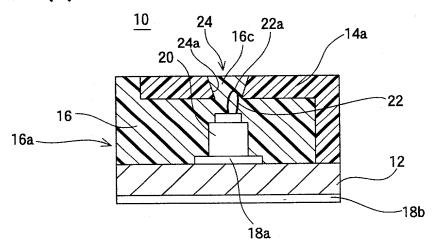
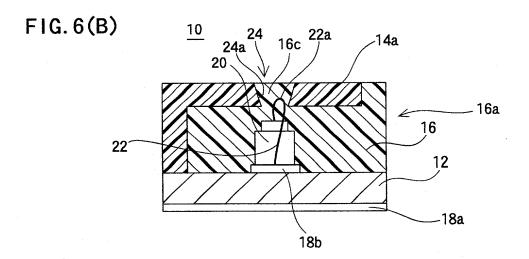


FIG. 6(A)

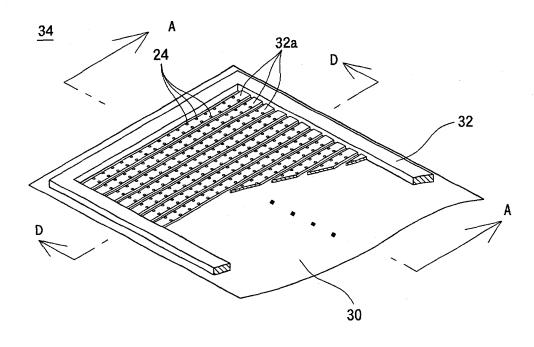




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FIG. 7(A) 24 32

FIG. 7(B)



Thereof

FIG. 8(A)

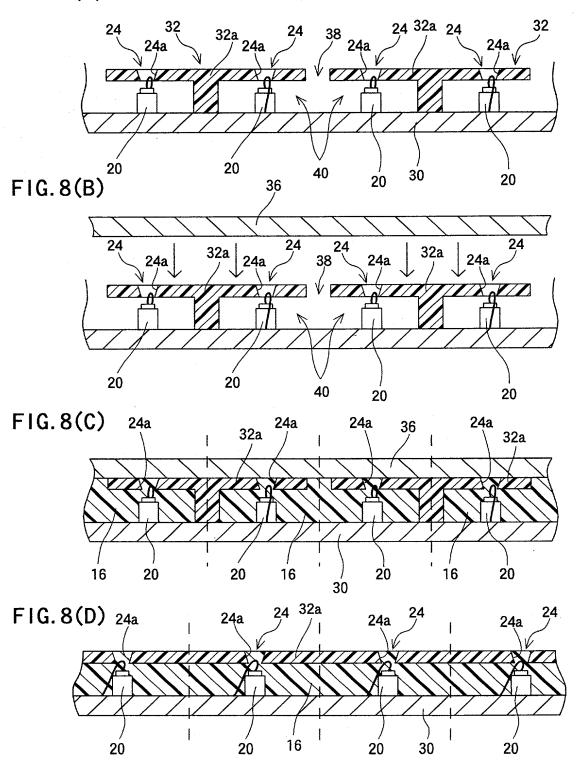


FIG.9

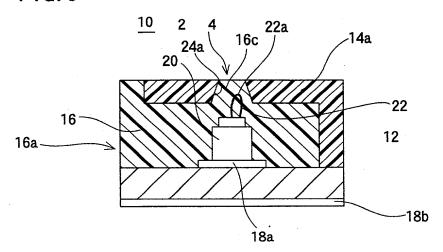
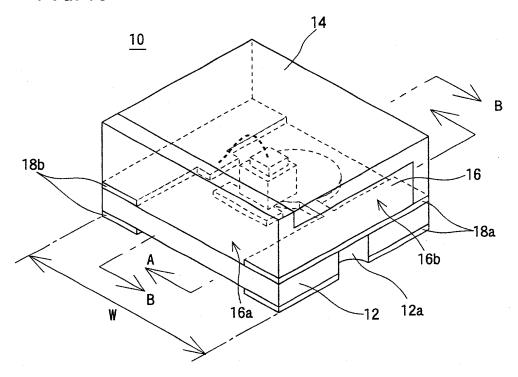


FIG. 10



Thereof

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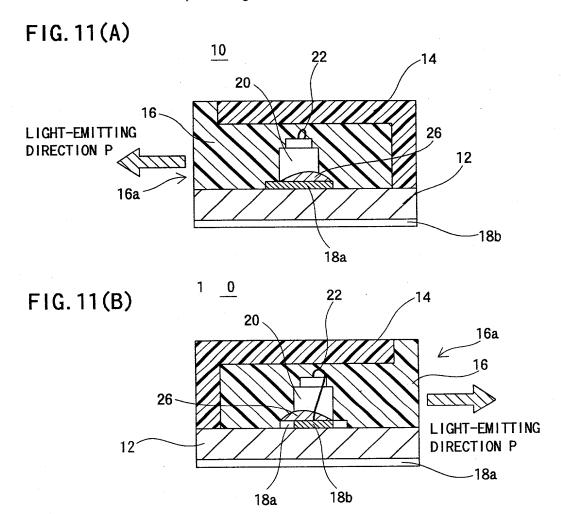
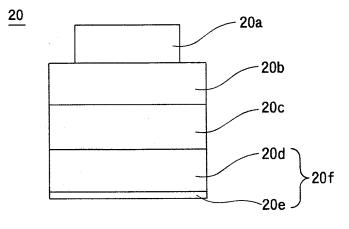
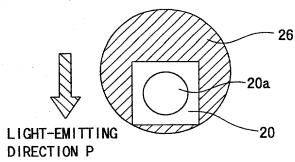


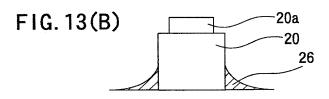
FIG. 12



Thereof

FIG. 13(A)





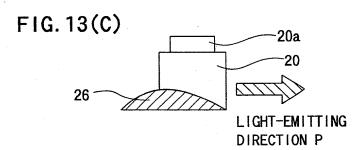


FIG. 13(D)

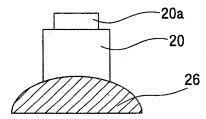


FIG. 14(A)

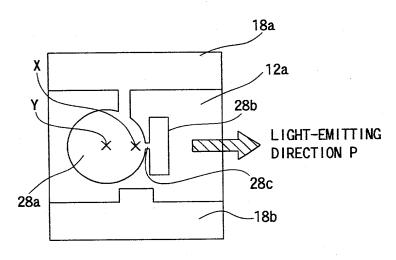
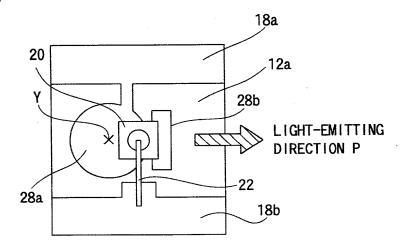


FIG. 14(B)



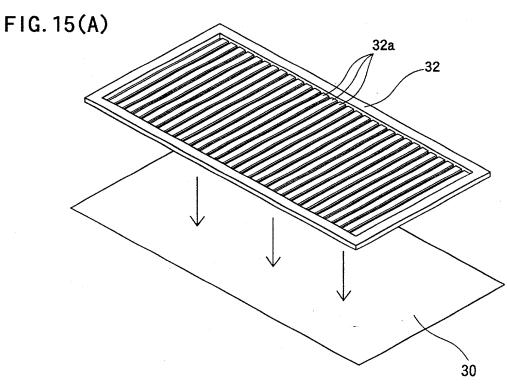
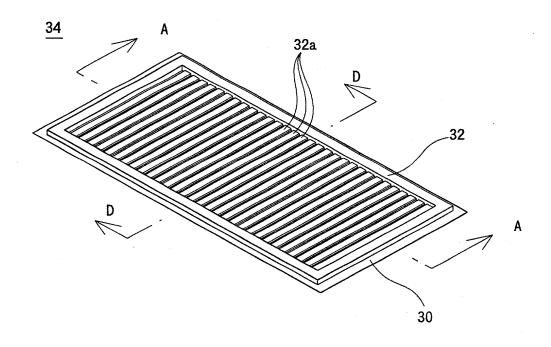
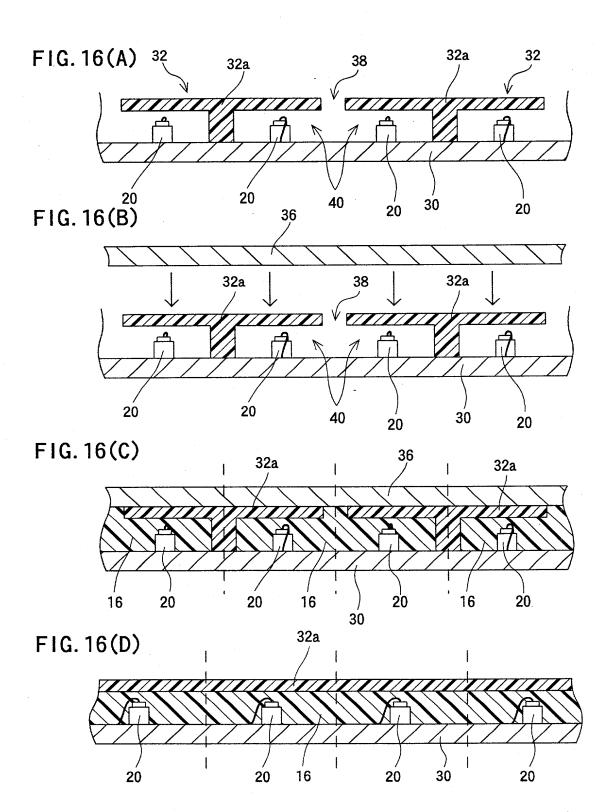
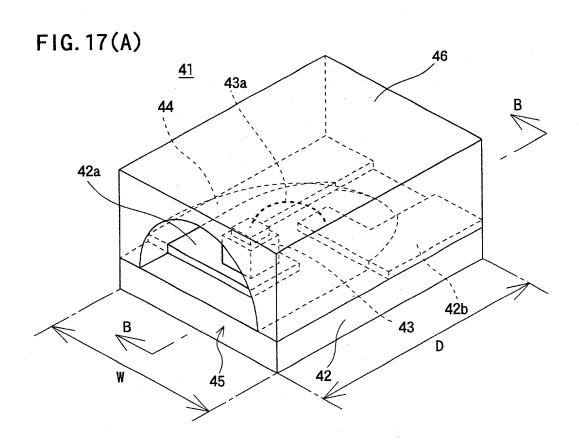


FIG. 15(B)







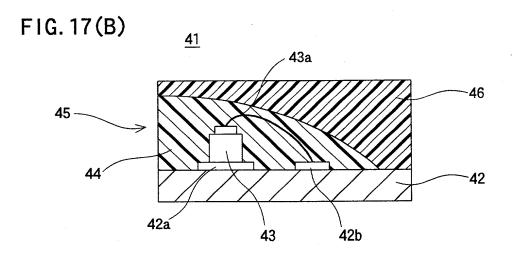


FIG. 18(A)

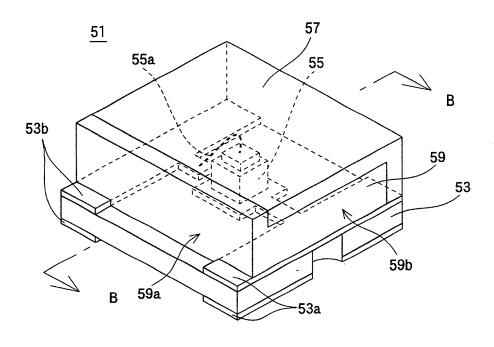


FIG. 18(B)

